

International **IR** Rectifier

Ultrafast Rectifier

MUR1520
MURB1520
MURB1520-1

Features

- Ultrafast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature

$$\begin{aligned} t_{rr} &= 35\text{ns} \\ I_{F(AV)} &= 15\text{Amp} \\ V_R &= 200\text{V} \end{aligned}$$

Description/Applications

International Rectifier's MUR.. series are the state of the art Ultra fast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultra fast recovery time.

The planar structure and the platinum doped life time control, guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, UPS, DC-DC converters as well as free-wheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

Parameters	Max	Units
V_{RRM} Peak Repetitive Peak Reverse Voltage	200	V
$I_{F(AV)}$ Average Rectified Forward Current Total Device, (Rated V_R), $T_C = 150^\circ\text{C}$	15	A
I_{FSM} Non Repetitive Peak Surge Current	200	
I_{FM} Peak Repetitive Forward Current (Rated V_R , Square wave, 20 KHz), $T_C = 150^\circ\text{C}$	30	
T_J, T_{STG} Operating Junction and Storage Temperatures	-65 to 175	°C

Case Styles		
MUR1520  TO-220AC	MURB1520  D2PAK	MURB1520-1  TO-262

MUR1520, MURB1520, MURB1520-1

Bulletin PD-20727 rev. B 01/01

International
ICR Rectifier

Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters		Min	Typ	Max	Units	Test Conditions
V_{BR} , V_r	Breakdown Voltage, Blocking Voltage	200	-	-	V	$I_R = 100\mu\text{A}$
V_F	Forward Voltage	-	-	1.05	V	$I_F = 15\text{A}$
		-	-	0.85	V	$I_F = 15\text{A}, T_J = 150^\circ\text{C}$
I_R	Reverse Leakage Current	-	-	10	μA	$V_R = V_R$ Rated
		-	-	500	μA	$T_J = 150^\circ\text{C}, V_R = V_R$ Rated
C_T	Junction Capacitance	-	55	-	pF	$V_R = 200\text{V}$
L_S	Series Inductance	-	8.0	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters		Min	Typ	Max	Units	Test Conditions
t_{rr}	Reverse Recovery Time	-	-	35	ns	$I_F = 1.0\text{A}, di_F/dt = 50\text{A}/\mu\text{s}, V_R = 30\text{V}$
		-	22	-		$T_J = 25^\circ\text{C}$
		-	39	-		$T_J = 125^\circ\text{C}$
I_{RRM}	Peak Recovery Current	-	1.6	-	A	$T_J = 25^\circ\text{C}$
		-	4.1	-		$T_J = 125^\circ\text{C}$
Q_{rr}	Reverse Recovery Charge	-	19	-	nC	$T_J = 25^\circ\text{C}$
		-	90	-		$T_J = 125^\circ\text{C}$

Thermal - Mechanical Characteristics

Parameters		Min	Typ	Max	Units	
T_J	Max. Junction Temperature Range	-	-	-65 to 175	°C	
T_{Stg}	Max. Storage Temperature Range	-	-	-65 to 175		
R_{thJC}	Thermal Resistance, Junction to Case	-	-	1.5	°C/W	
$R_{thJA}^{(1)}$	Thermal Resistance, Junction to Ambient	-	-	50		
$R_{thCS}^{(2)}$	Thermal Resistance, Case to Heatsink	-	0.5	-		
W_t	Weight	-	2.0	-	g	
		-	0.07	-	(oz)	
Mounting Torque		6.0	-	12	Kg-cm	
		5.0	-	10	lbf.in	

⁽¹⁾ Typical Socket Mount

⁽²⁾ Mounting Surface, Flat, Smooth and Greased

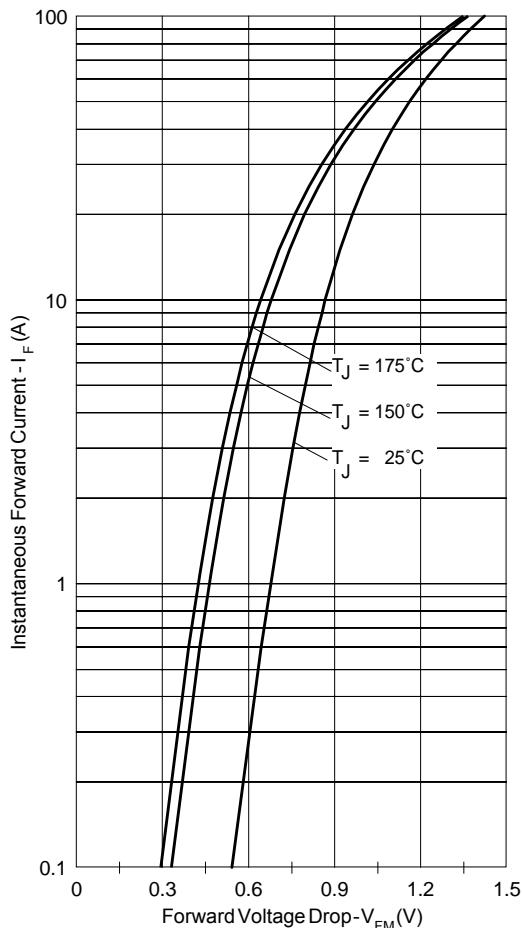


Fig.1-Typical Forward Voltage Drop Characteristics

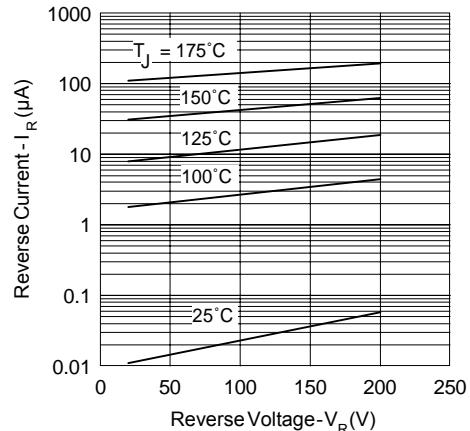


Fig.2-Typical Values Of Reverse Current Vs. Reverse Voltage

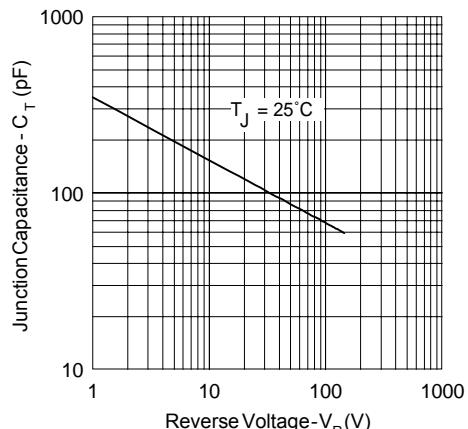


Fig.3-Typical Junction Capacitance Vs. Reverse Voltage

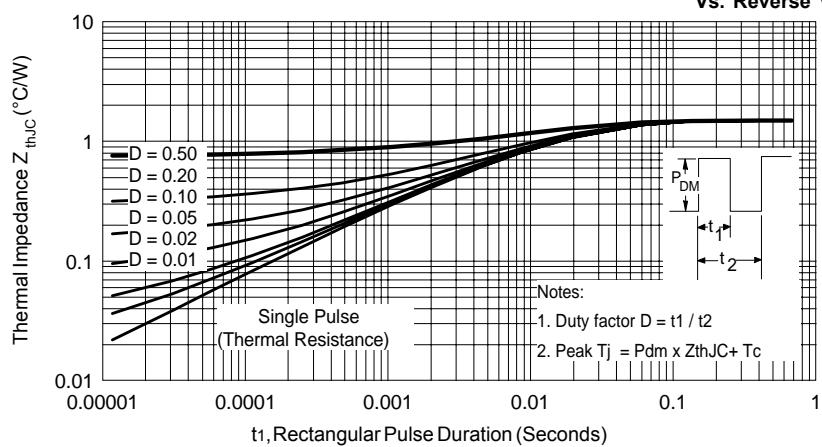


Fig.4 -Max. Thermal Impedance Z_{thJC} Characteristics

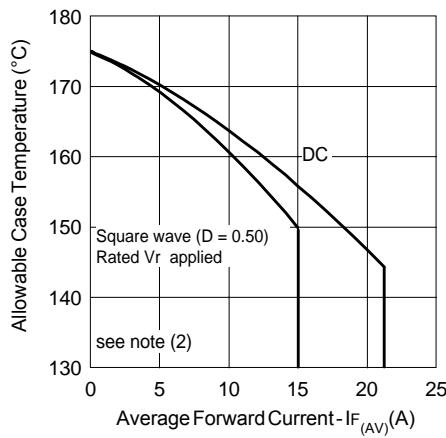


Fig. 5 - Max. Allowable Case Temperature Vs. Average Forward Current

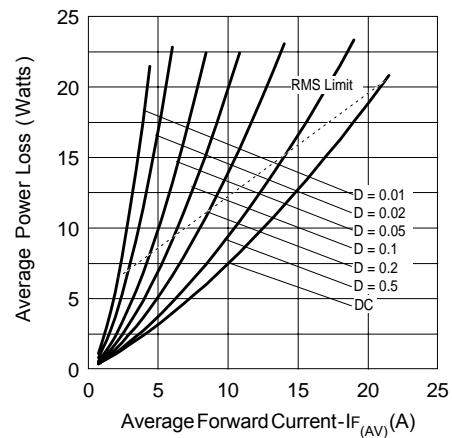
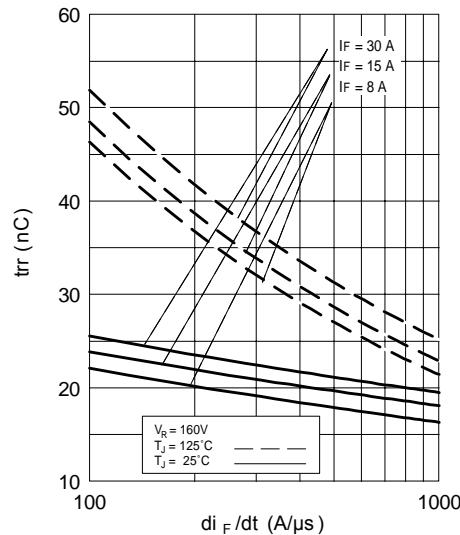
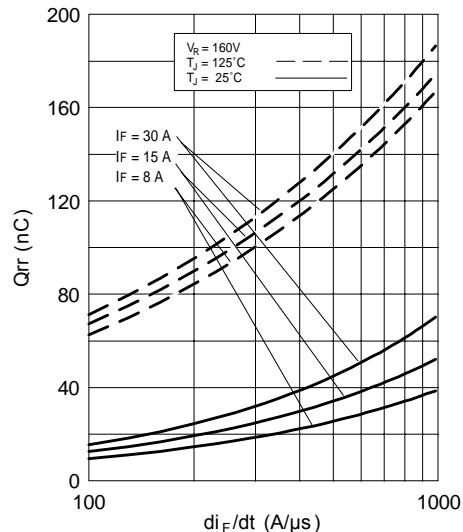


Fig. 6 - Forward Power Loss Characteristics

Fig. 7 - Typical Reverse Recovery vs. di_F/dt Fig. 8 - Typical Stored Charge vs. di_F/dt

(2) Formula used: $T_C = T_J - (P_d + P_{d_{REV}}) \times R_{thJC}$;
 $P_d = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $P_{d_{REV}} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$; $I_R @ V_{R1} = \text{rated } V_R$

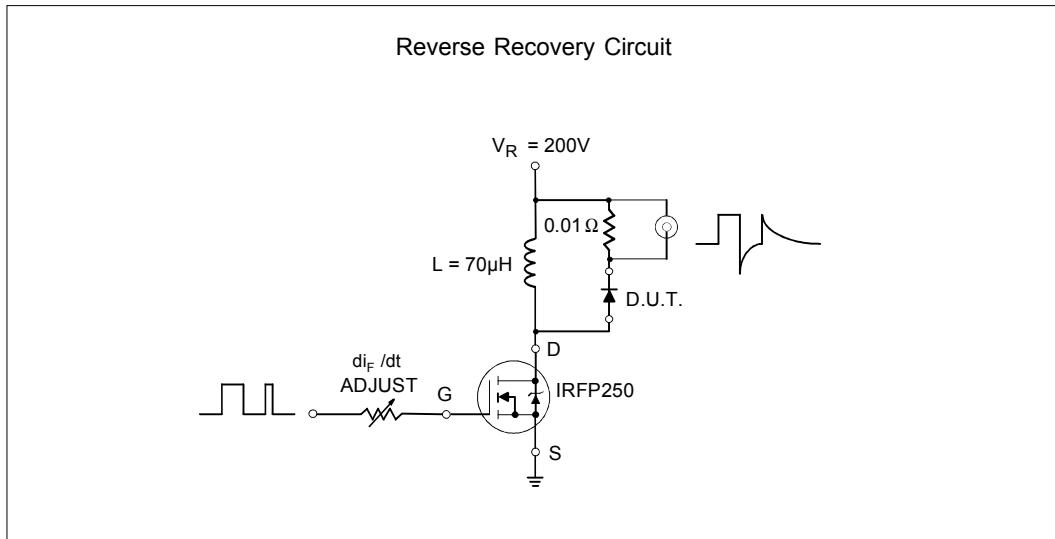


Fig. 9- Reverse Recovery Parameter Test Circuit

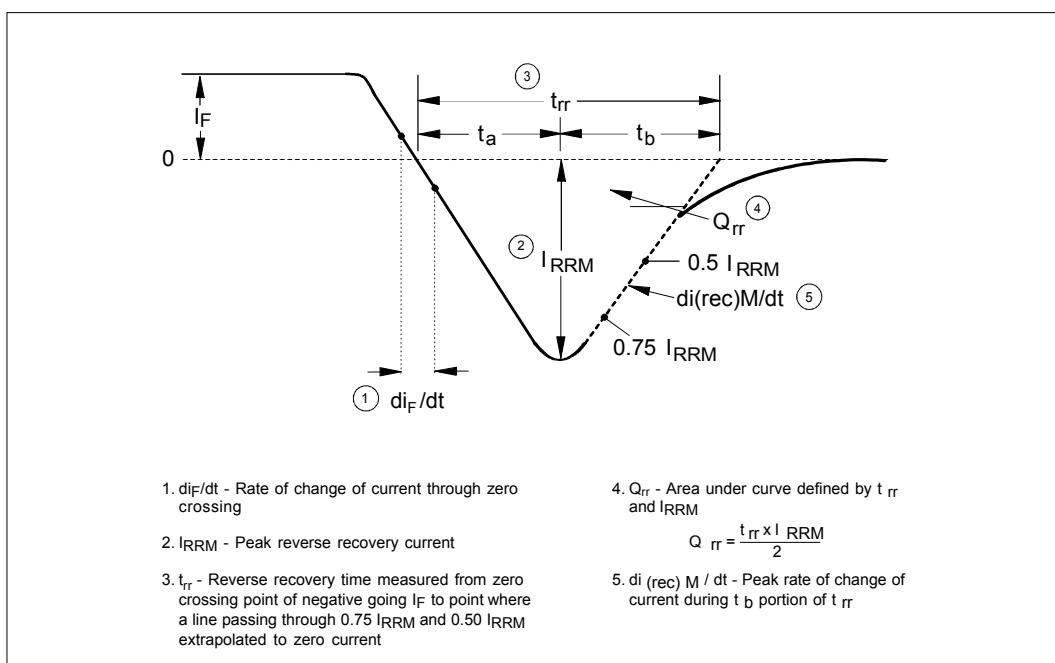
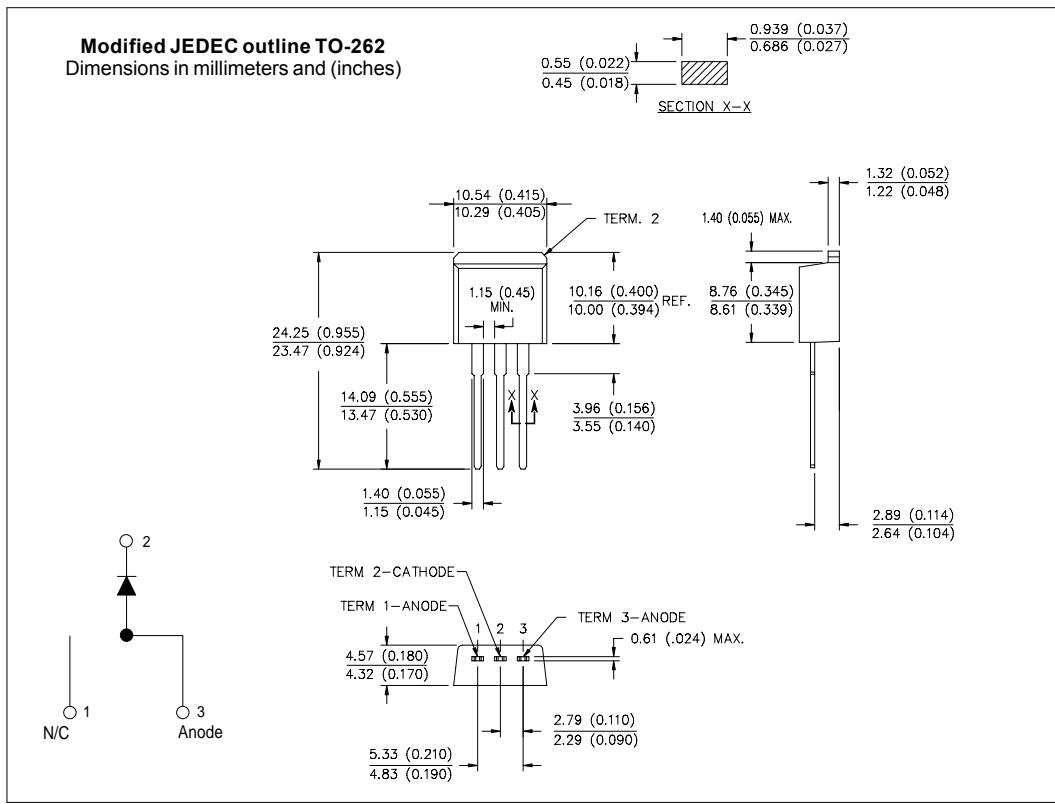
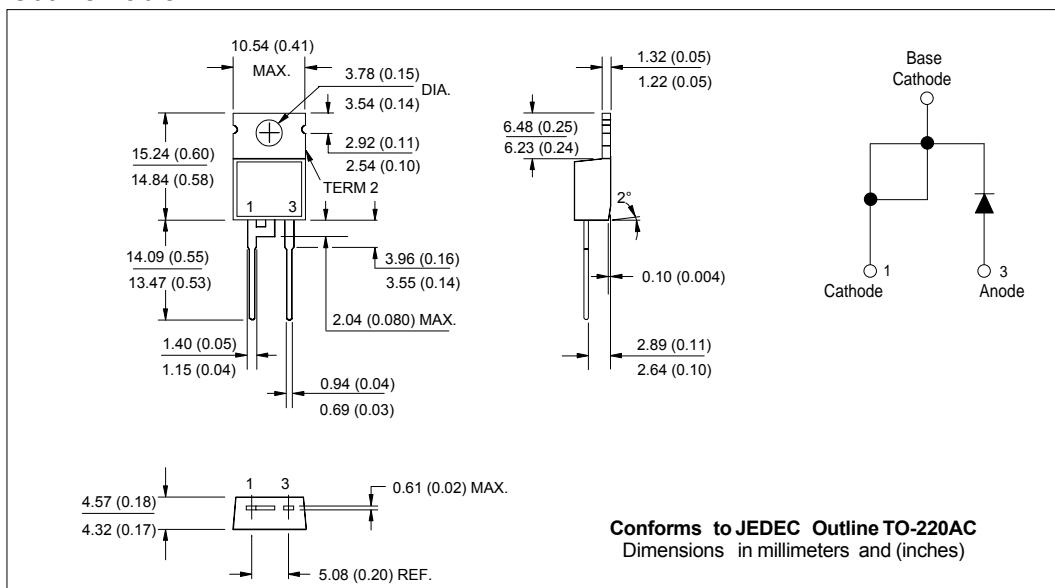
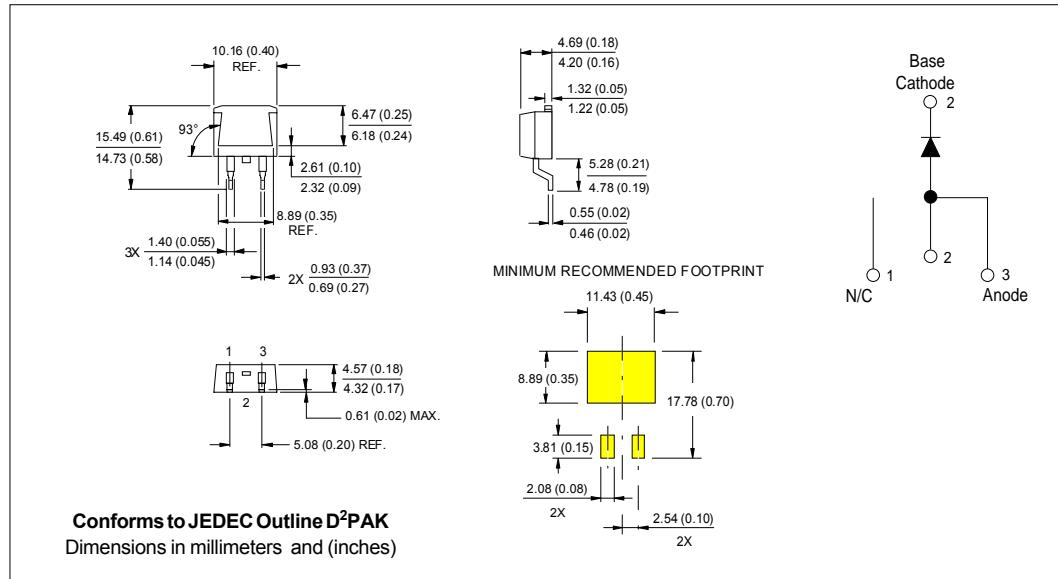


Fig. 10 - Reverse Recovery Waveform and Definitions

Outline Table



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Ordering Information Table

Device Code					
MUR	B	15	20	CT	-1
(1)	(2)	(3)	(4)	(5)	(6)
1	- Ultrafast MUR Series				
2	- B = D ² Pak/TO-262				
	None = TO-220AC				
3	- Current Rating (15 = 15A)				
4	- Voltage Rating (20 = 200V)				
5	- CT = Center Tap (Dual) TO-220/D ² PAK/TO-262				
6	- "-1" = TO-262 Option				

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